

Device Modeling Report

COMPONENTS:

DIODE/ SCHOOTTKY RECTIFIER / STANDARD

PART NUMBER: DE3S6M

MANUFACTURER: SHINDENGEN

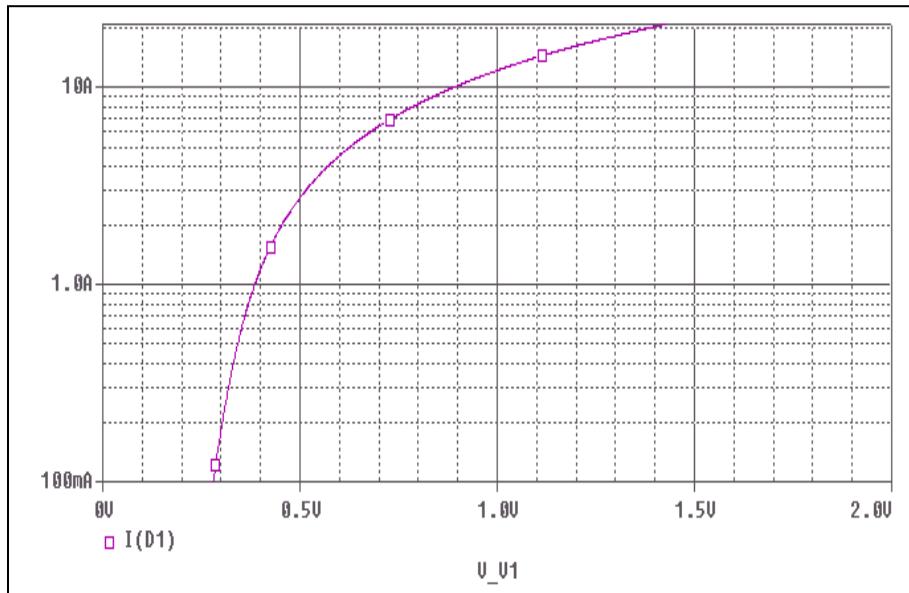


Bee Technologies Inc.

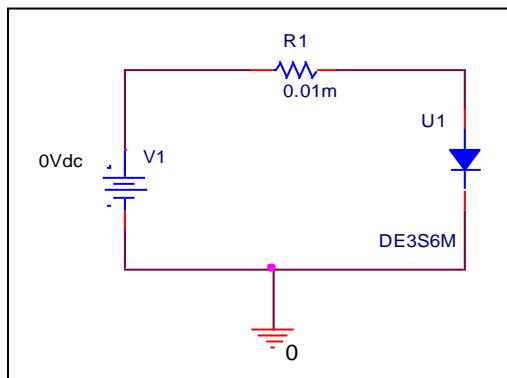
PSpice model parameter	Model description
IS	Saturation Current
N	Emission Coefficient
RS	Series Resistance
IKF	High-injection Knee Current
CJO	Zero-bias Junction Capacitance
M	Junction Grading Coefficient
VJ	Junction Potential
ISR	Recombination Current Saturation Value
BV	Reverse Breakdown Voltage(a positive value)
IBV	Reverse Breakdown Current(a positive value)
TT	Transit Time
EG	Energy-band Gap

Forward Current Characteristic

Circuit Simulation Result

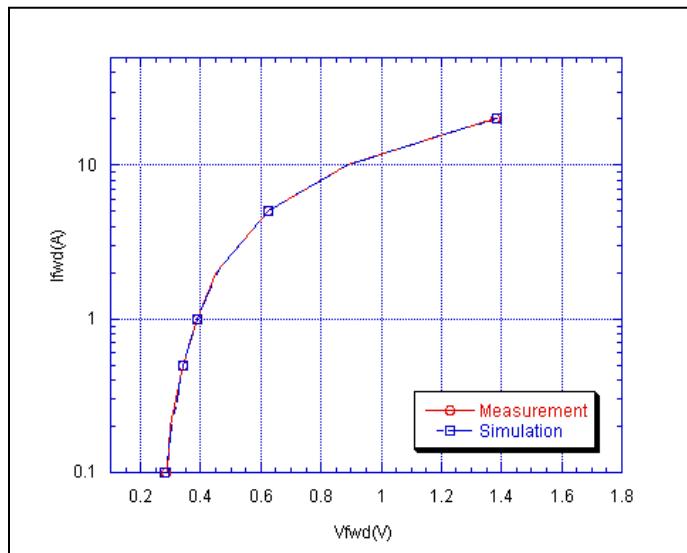


Evaluation Circuit



Comparison Graph

Circuit Simulation Result

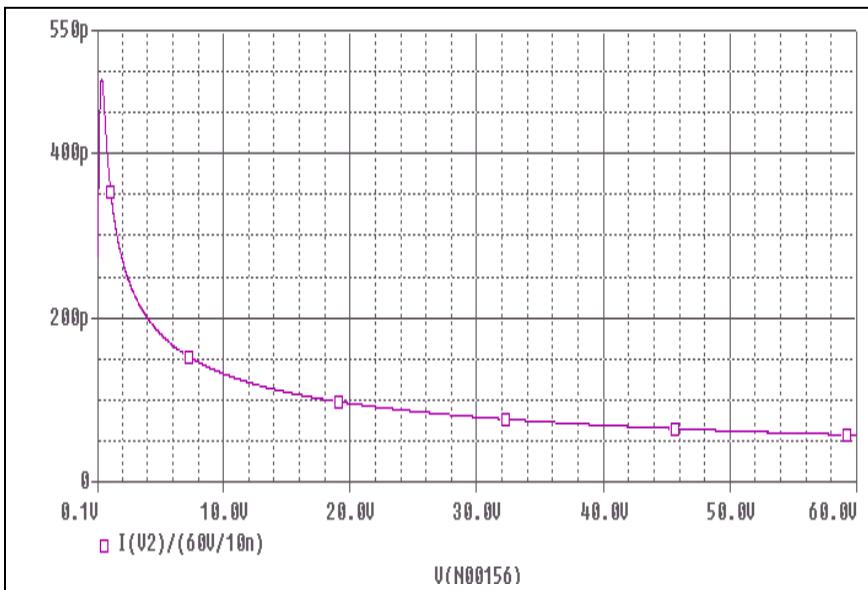


Simulation Result

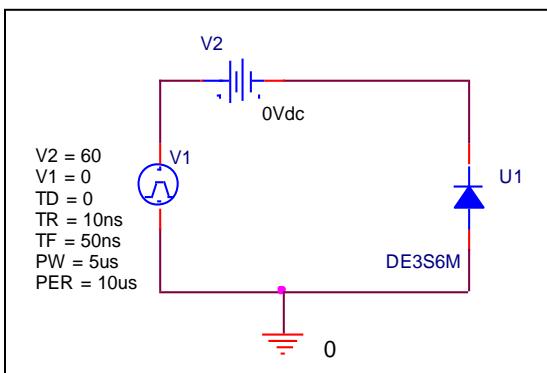
$I_{fwd}(A)$	$V_{fwd}(V)$ Measurement	$V_{fwd}(V)$ Simulation	%Error
0.1	0.284	0.282	-0.70
0.2	0.300	0.303	1.00
0.5	0.340	0.341	0.29
1	0.390	0.386	-1.03
2	0.450	0.453	0.67
5	0.625	0.626	0.16
10	0.890	0.889	-0.11
20	1.380	1.383	0.22

Junction Capacitance Characteristic

Circuit Simulation Result

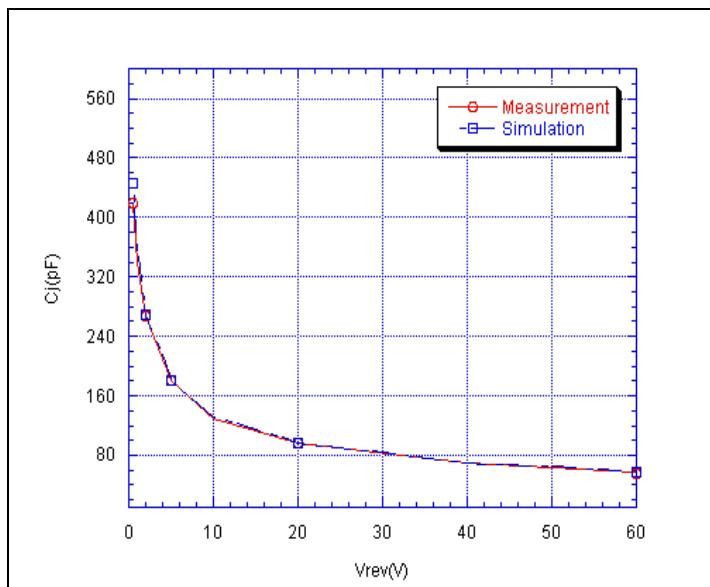


Evaluation Circuit



Comparison Graph

Circuit Simulation Result



Simulation Result

Vrev(V)	Cj(pF) Measurement	Cj(pF) Simulation	%Error
0.5	428.000	445.000	3.97
1	345.000	358.000	3.77
2	267.000	270.000	1.12
5	180.000	180.300	0.17
10	130.000	131.600	1.23
20	96.000	95.500	-0.52
60	55.000	57.100	3.82